



High curvature sensors based on flexoelectric effect in soft semi-conducting polymer films

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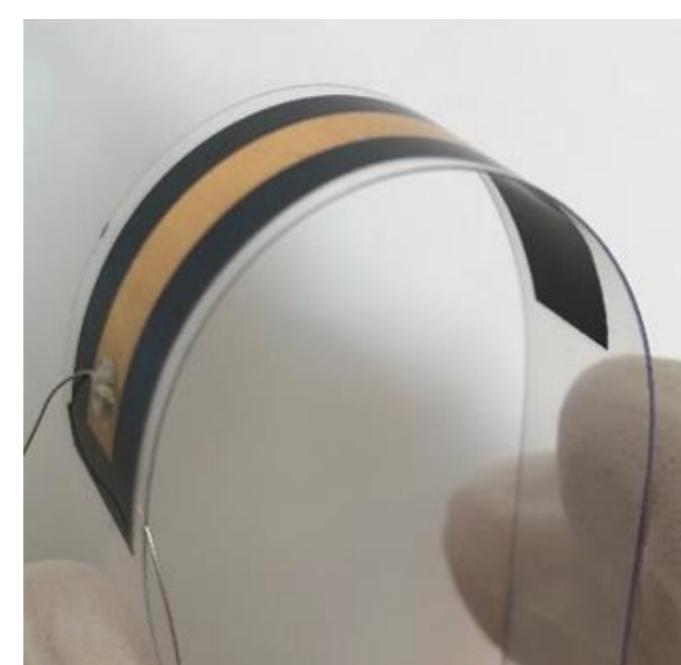
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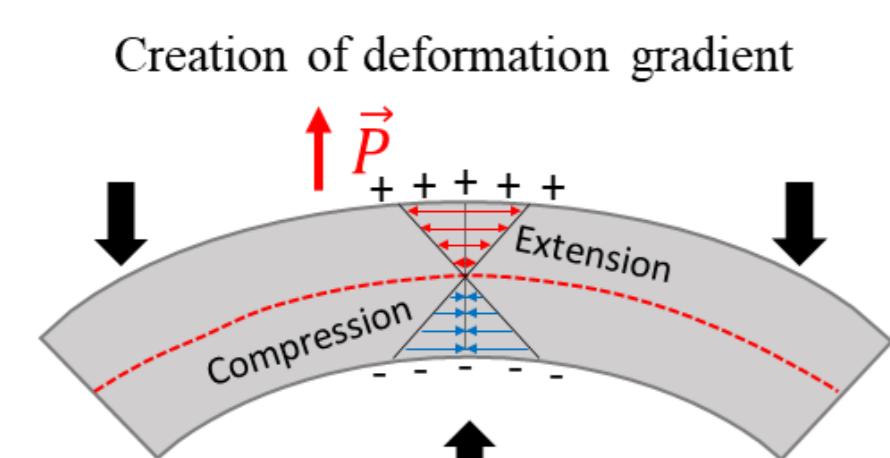
Context

- Objective :** To obtain a high-curvature sensor based on flexoelectric effect
- Solution :** PEDOT:PSS free standing thin film
- Lines of research :**
 - Optimize the flexoelectric sensor

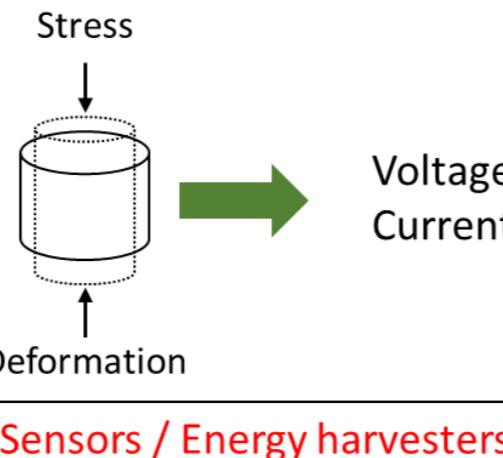


Flexoelectricity ? (direct and reverse effect) ①

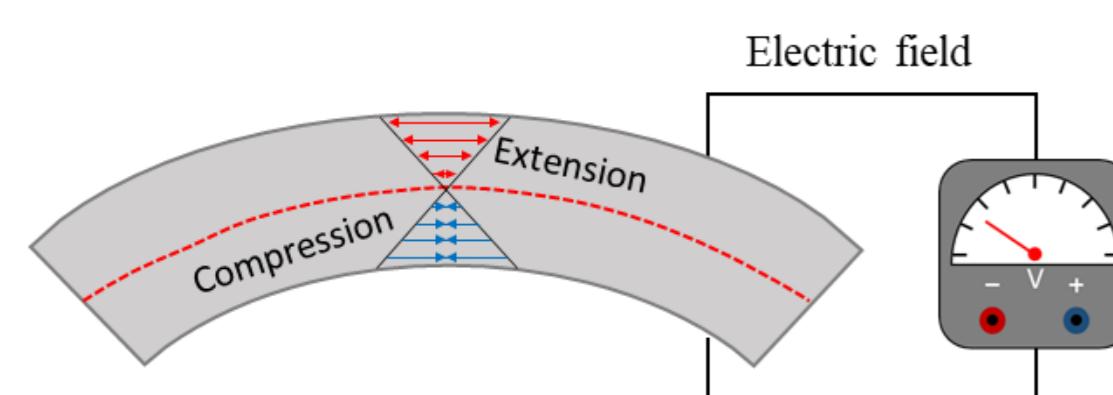
Direct effect : electrical polarization P_i is induced by a deformation gradient



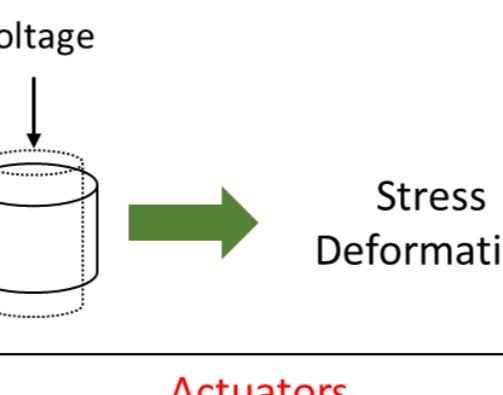
$$P_i = \mu_{klkj} \frac{\partial S_{kl}}{\partial x_j}$$



Reverse effect : Mechanical stress T_{ij} induced by an electric field gradient (E_k)



$$T_{ij} = \mu_{ijkj} \frac{\partial E_k}{\partial x_i}$$



Piezoelectricity vs Flexoelectricity ②

Piezoelectricity

Flexoelectricity

$$P_{\text{piezo}} = e \cdot S$$

$S = \text{deformation}$

No centrosymmetric materials

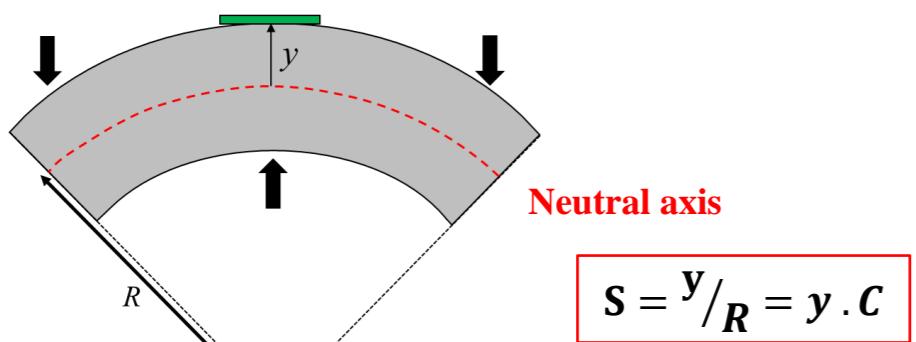
Electric field polarization : YES

Piezoelectric coefficient $e \approx 10 \text{ C/m}^2$

Effet de vieillissement

Deformation $S \sim 1\%$

S depends on the position of the sensor relative to the neutral axis!



$$P_{\text{flexo}} = \mu \frac{\partial S}{\partial x} = \mu \cdot C$$

$C = \text{curvature}$

Universal coupling

NO

Flexoelectric coefficient $\mu \approx 10^{-4} \text{ C/m}$

Pas de vieillissement

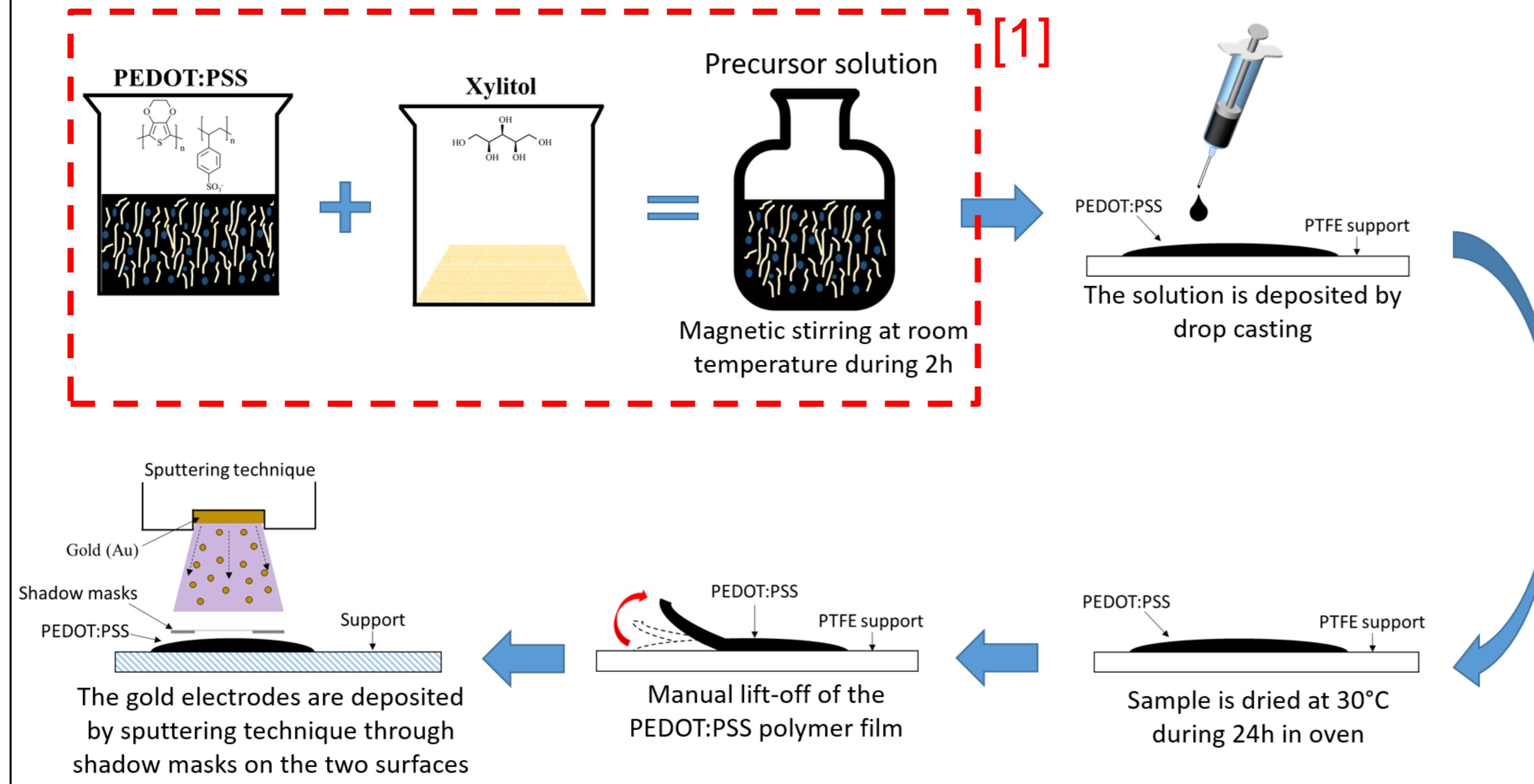
Curvature $C = \frac{\partial S}{\partial x} \text{ to } 10^6 \text{ m}^{-1}$

C is constant throughout the thickness!

Curvature varies inversely with thickness and mechanical rigidity

Flexible films

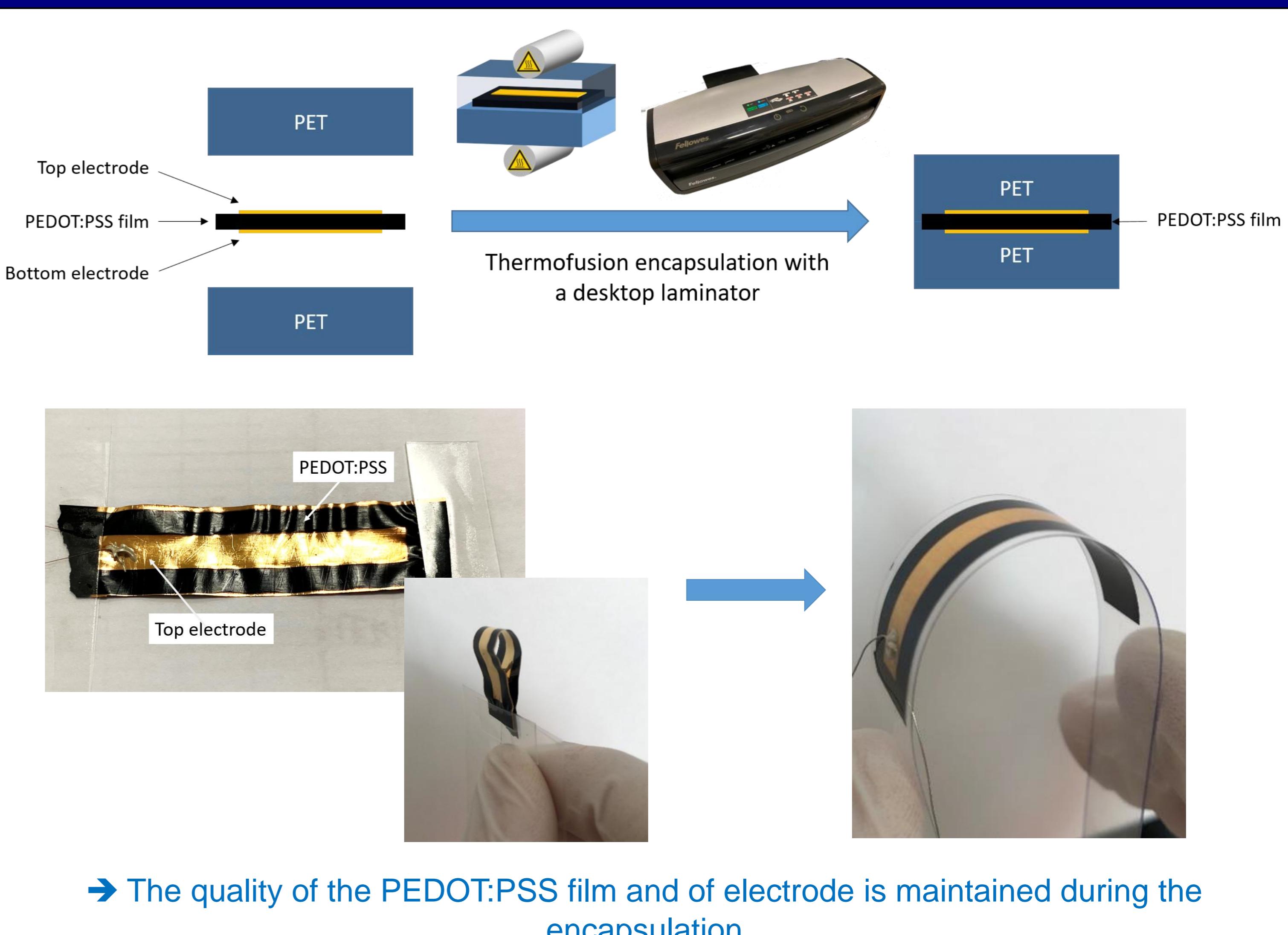
PEDOT:PSS thin film preparation ③



Research prospects

- Optimization of curvature sensor
- Realize a circuit for sensor management
- Making a green curvature sensor
 - biopolymer or biodegradable polymer
 - eco-friendly manufacturing process

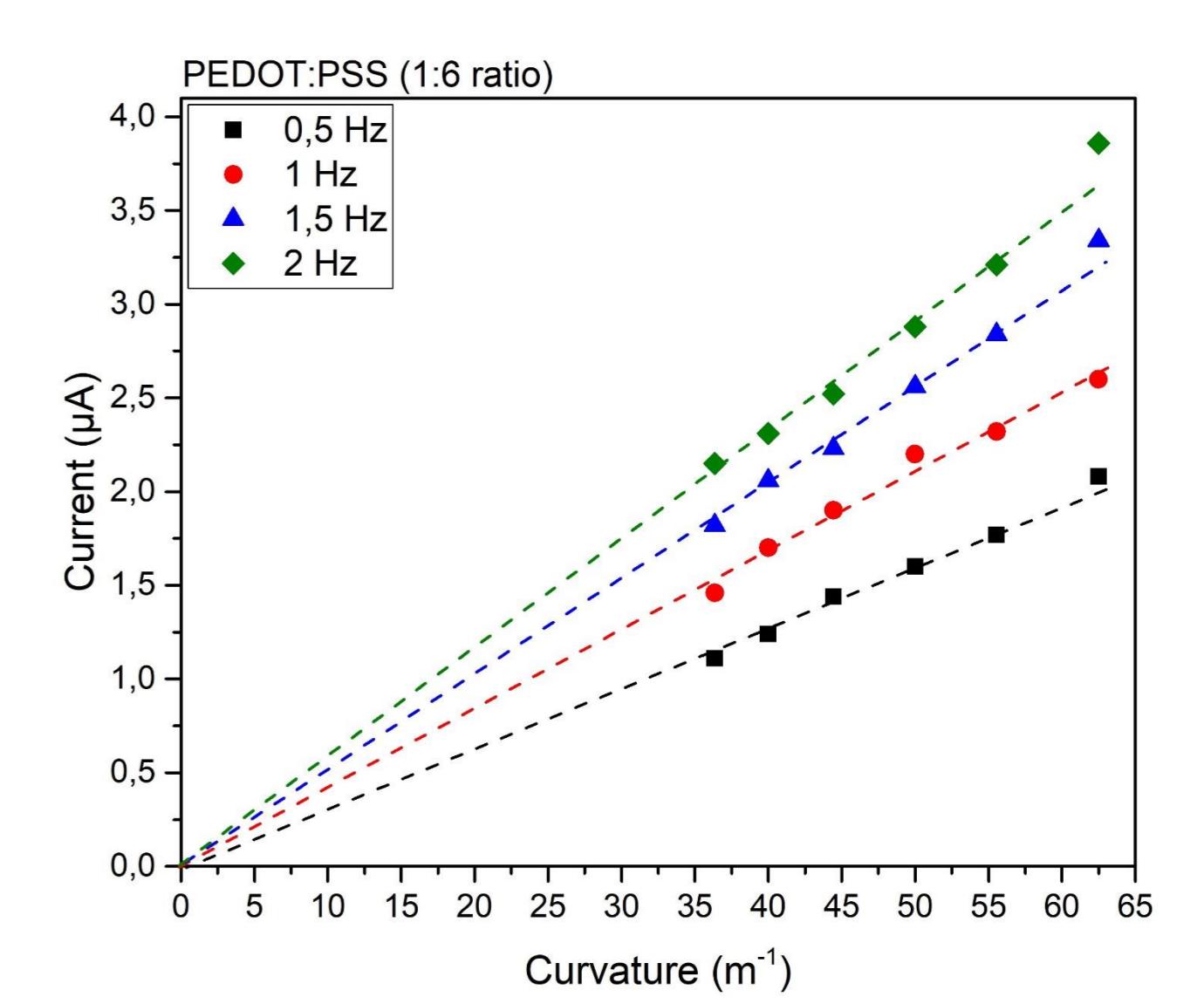
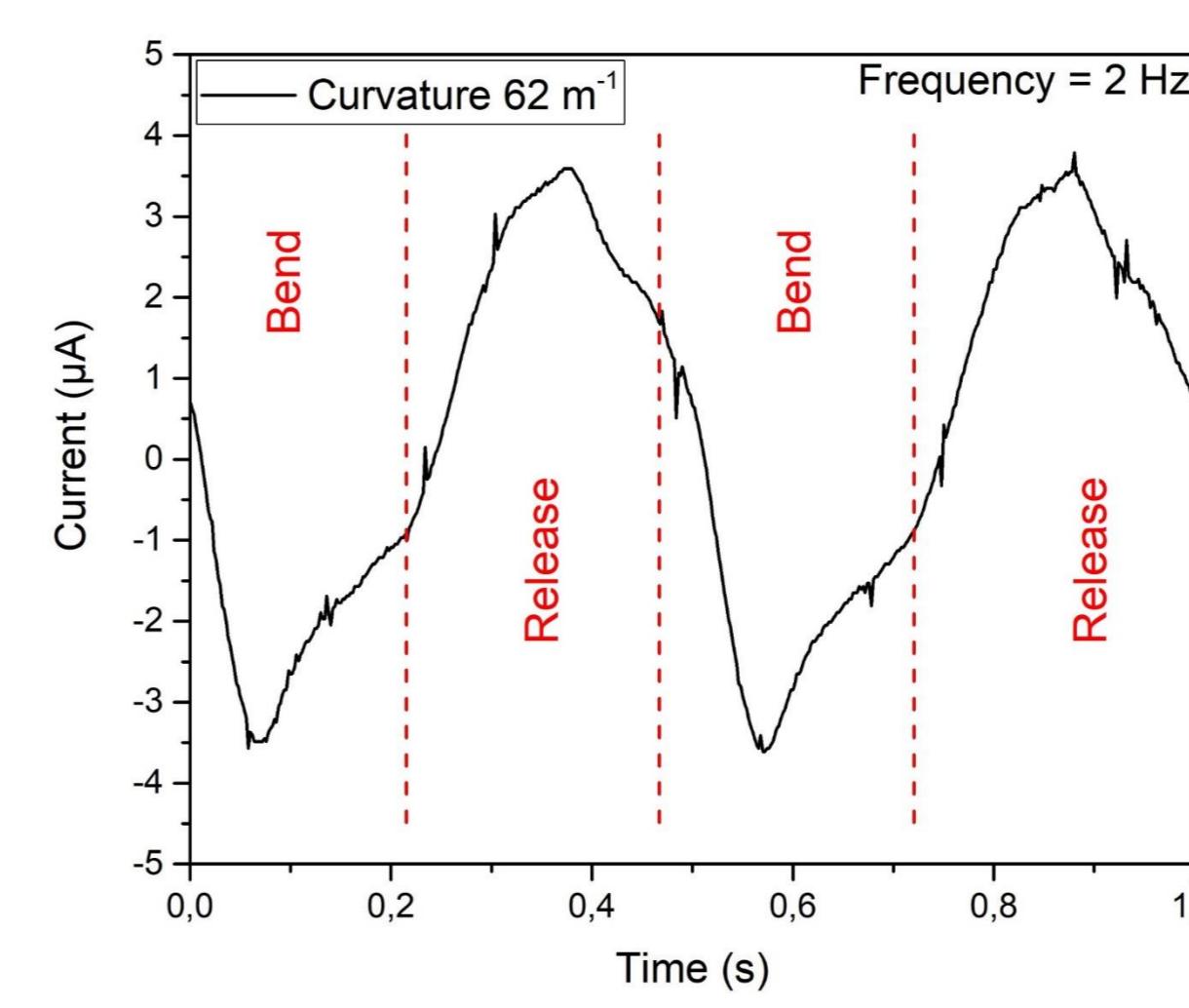
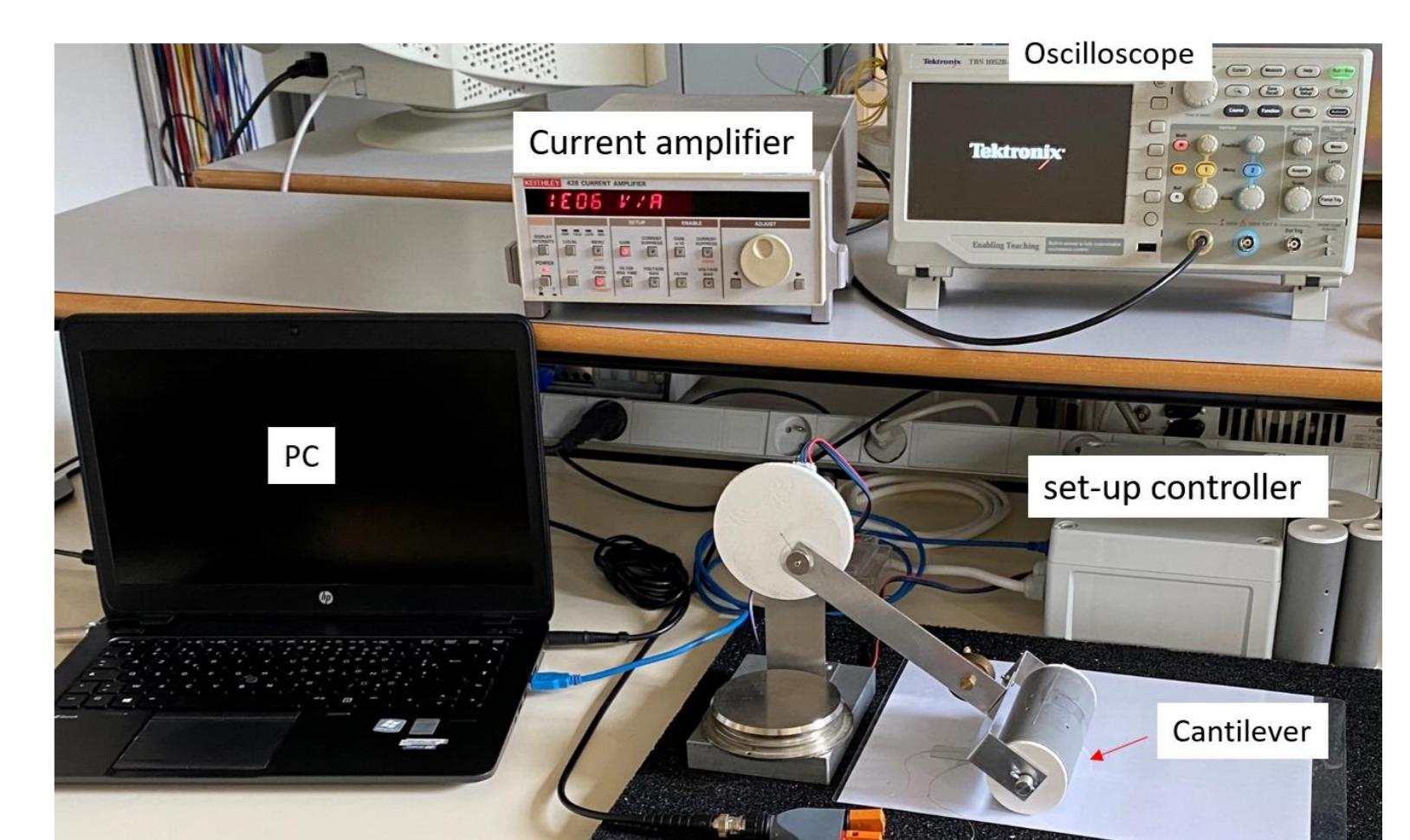
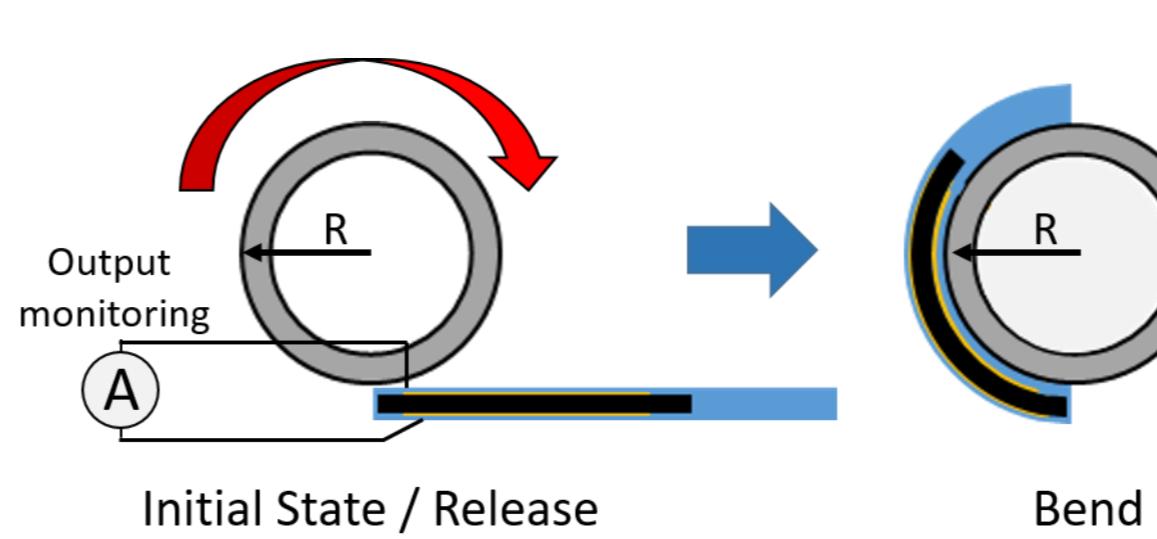
Preparation of the flexoelectric sensors ④



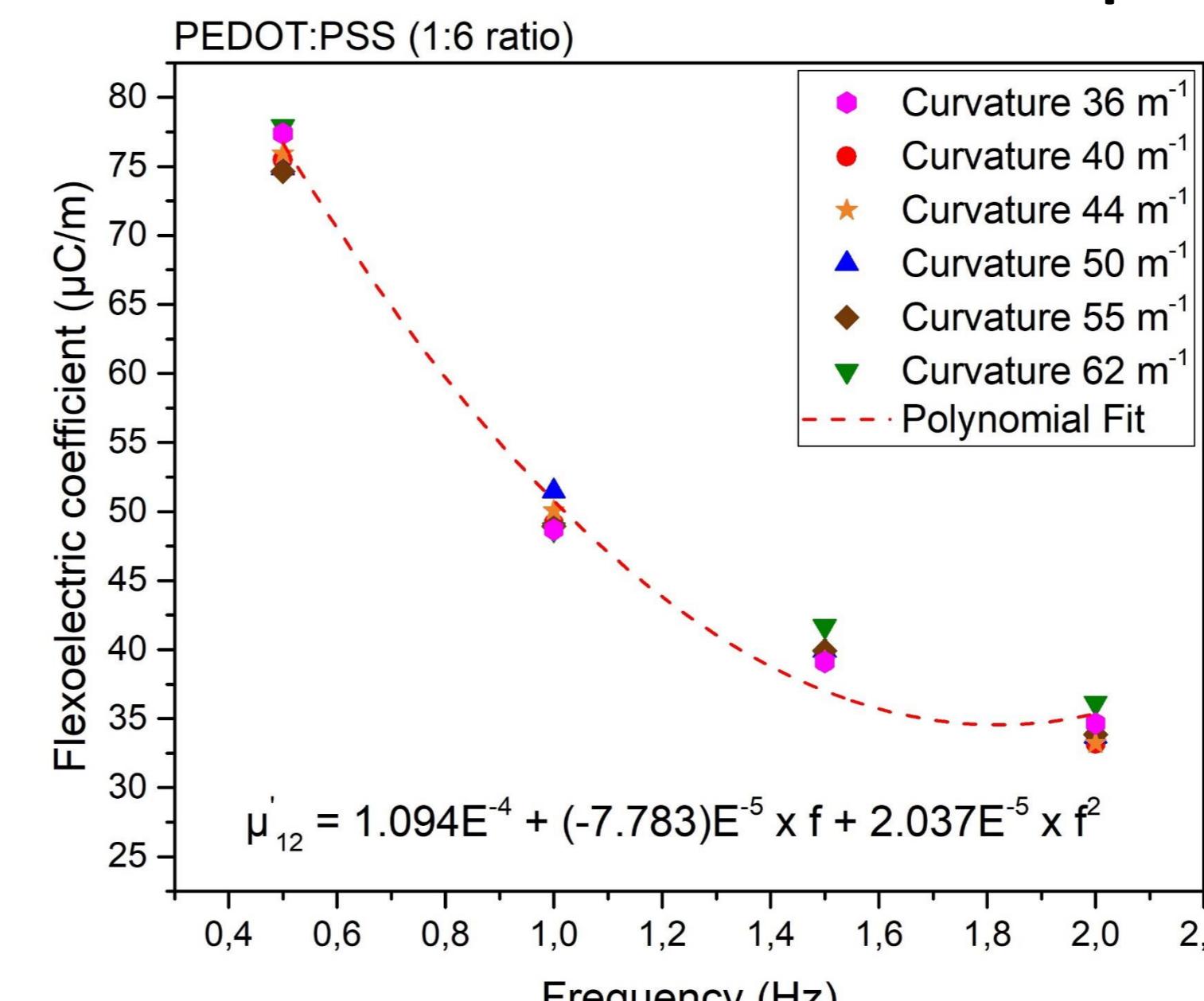
Experiments ⑤

Schematic of experimental setup

$$\mu'_{12} = \frac{i}{2\pi f b l C}$$



Schematic of experimental setup



$$C = \frac{i}{2\pi f b l \mu'_{12}(f)}$$

High-curvature sensor based on flexoelectric effect

REFERENCE :

- [1] Saadeh, M., Frère, P., and Guiffard, B. (2020). Revealing the flexoelectric-like response of poly(3,4-ethylenedioxythiophene):poly(styrenesulfonate) thin films. *Polymers for Advanced Technologies* 31, 2632–2639. 10.1002/pat.4989.